

UNITED STATES PATENT AND TRADEMARK OFFICE





			www.uspto.gov	
APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/961,248	09/25/2001	Hidetaka Hattori	214391US2S	7284
22850	7590 08/27/2002			L
OBLON SPIVAK MCCLELLAND MAIER & NEUSTADT PC			EXAMINER	
FOURTH FLOOR 1755 JEFFERSON DAVIS HIGHWAY ARLINGTON, VA 22202		FARAHANI, DANA		
			ART UNIT	PAPER NUMBER
			2814	
			DATE MAILED: 08/27/2002	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)				
Office Action Commons	09/961,248	HATTORI, HIDETAKA				
Office Action Summary	Examiner	Art Unit				
The MAN INC DATE of this communication and	Dana Farahani	2814				
Th MAILING DATE of this communication app ars on the cover sheet with the correspond nc address Period for Reply						
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely. - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication. - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). - Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b). Status						
1) Responsive to communication(s) filed on 12 J	<u>une 2002</u> .					
2a)⊠ This action is FINAL . 2b)□ Thi	s action is non-final.					
3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.						
Disposition of Claims						
4) Claim(s) 1-40 is/are pending in the application.						
4a) Of the above claim(s) is/are withdrawn from consideration.						
5) Claim(s) is/are allowed.						
6)⊠ Claim(s) <u>1-40</u> is/are rejected.						
7) Claim(s) is/are objected to.						
8) Claim(s) are subject to restriction and/or election requirement.						
Application Papers						
9) The specification is objected to by the Examiner.						
10) The drawing(s) filed on is/are: a) accepted or b) objected to by the Examiner.						
Applicant may not request that any objection to the	•	• • •				
11)☐ The proposed drawing correction filed on is: a)☐ approved b)☐ disapproved by the Examiner.						
If approved, corrected drawings are required in reply to this Office action.						
12) The oath or declaration is objected to by the Examiner.						
Priority under 35 U.S.C. §§ 119 and 120						
13) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).						
a)⊠ All b)☐ Some * c)☐ None of:						
1. Certified copies of the priority documents have been received.						
2. Certified copies of the priority documents have been received in Application No						
 Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received. 						
14) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. § 119(e) (to a provisional application).						
a) ☐ The translation of the foreign language provisional application has been received. 15)☐ Acknowledgment is made of a claim for domestic priority under 35 U.S.C. §§ 120 and/or 121.						
Attachment(s)						
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449) Paper No(s)	5) Notice of Informal	y (PTO-413) Paper No(s) Patent Application (PTO-152)				

Art Unit: 2814

DETAILED ACTION

Claim Rejections - 35 USC § 102

1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- 2. Claims 1-3, 11-13, 21-23, and 31-33 are rejected under 35 U.S.C. 102(b) as being anticipated by Okabe et al., hereinafter Okabe (U.S. 5,973,338), previously cited.

Okabe discloses in figure 6, a semiconductor device comprising a base layer 67 of a first conductivity type; a base layer 65 of a second conductivity type selectively formed on one surface of the base layer of the first conductivity type; an emitter layer 69 of the first conductivity type, and a source layer 66 of the first conductivity type, selectively formed on the surface of the base layer of the second conductivity type; a collector layer 66, and drain layer 64, selectively formed on one of the one surface and a the other surface of the base layer of the first conductivity type; a first main electrode, S, formed on the collector layer; a second main electrode 62 formed on the emitter layer of the first conductivity type and on the base layer of the second conductivity type; and a gate electrode G formed above part of the base layer of the second conductivity type which lies between the one of the emitter layer and the base layer of the first conductivity type with first and second gate insulating films, above and below layer 63, respectively, disposed there between; wherein the capacitance of a capacitor formed of

Art Unit: 2814

the second gate insulating film above layer 63 is different from that of a capacitor formed of the first gate insulating film below layer 63, as can be seen in figure 6.

Regarding claims 2, 12, 22, and 32, the first gate insulating film above layer 63 is formed in a portion near the one of the emitter layer and source layer 66 of the first conductivity type and the second gate insulating film below layer 63 is formed in a portion near the base layer of the first conductivity type.

Regarding claims 3, 13, 23, and 33, the thickness of the second gate insulating film is larger than that of the first gate insulating film.

Claim Rejections - 35 USC § 103

- 3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 4. Claims 4, 14, 24, and 34 are rejected under 35 U.S.C. 103(a) as being unpatentable over Okabe, as applied to claims 1-3 above, and further in view of Kapoor (U.S. 6,300,663), previously cited.

Okabe discloses the claimed invention except for disclosing the dielectric constants of the gate insulating films are different.

Kapoor discloses gate insulating films where the dielectric constant of the first insulating film is higher than the dielectric constant of the second insulating film (see column 4, claim 8). Therefore, it would have been obvious to one of ordinary skill in the

Art Unit: 2814

art at the time of the invention to use gate insulator layers of different dielectric constants so the layers would have different capacitances, thus less area on the semiconductor chip.

5. Claims 5, 15, 25, and 35 are rejected under 35 U.S.C. 103(a) as being unpatentable over Okabe, as applied to claim 2 above.

Okabe discloses the claimed invention, but dose not disclose an inclination on the side of the emitter layer of the first conductivity type is smaller than that on the side of the base layer of the first conductivity type. However, it would have been obvious to one of ordinary skill in the art at the time of the invention to make the inclination on the side of the emitter layer smaller so it would have larger capacitance, thus less area on the semiconductor chip

6. Claims 6-10, 16-20, 26-30, and 36-40 are rejected under 35 U.S.C. 103(a) as being unpatentable over Okabe, and Okabe in view of Kapoor, as applied to claims1-3 and 4 above, respectively, and further in view of Takahashi et al., hereinafter Takahashi (U.S 6,331,466), previously cited.

Okabe in view of Kapoor renders obvious the claimed invention, as above discussed, except for the semiconductor device wherein the gate electrode is buried in a trench with the first and second gate insulating films disposed there between to form a trench structure.

Takahashi discloses in figure 1, a gate electrode 210 is buried in a trench 207, which range from the surface to the layer beneath the top layer; and insulating film 209. Furthermore Takahashi discloses such an structure enhances the integration degree

Art Unit: 2814

(see column 1, lines 35-40). Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention to use gate trenches because of its easy miniaturization.

Response to Arguments

7. Applicant's amendment filed May 20, 2002, including adding new claims 21-40, is considered. Accordingly, they are included under rejected claims in this Office action.

Conclusion

8. Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

Art Unit: 2814

Page 6

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Dana Farahani whose telephone number is (703)305-1914. The examiner can normally be reached on M-F 8:00AM - 5:00PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Olik Chaudhuri can be reached on (703)306-2794. The fax phone numbers for the organization where this application or proceeding is assigned are (703) 308-7722 for regular communications and (703) 308-3432 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-0956.

Dana Farahani August 26, 2002

> OMA Christiburi Copin Assoly Count Swaminer Taxonology Center 2000